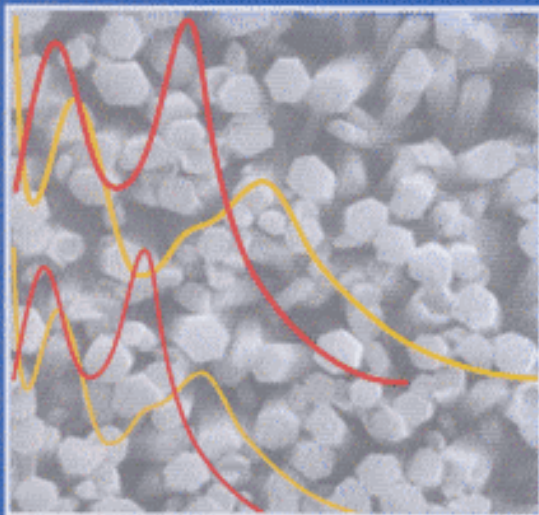


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# Electrochemistry of Nanomaterials

Edited by Gary Hodes



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